SPICE Device Model SUM90N04-3m3P



Vishay Siliconix

N-Channel 40 V (D-S) MOSFET

DESCRIPTION

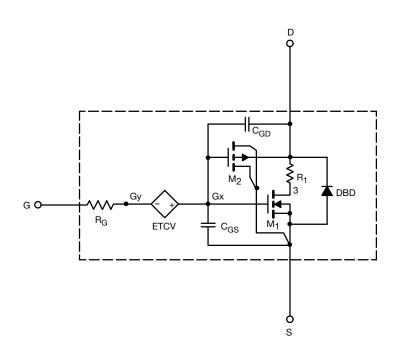
The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the - 55 °C to + 125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

SUBCIRCUIT MODEL SCHEMATIC

CHARACTERISTICS

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- Model the Gate Charge



Note

 This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

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SPECIFICATIONS $T_J = 25 \text{ °C}$, unless otherwise noted					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS},I_{D}=250\;\mu A$	1.3	-	V
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 22 \text{ A}$	0.0027	0.0027	Ω
		$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 20 \text{ A}$	0.0034	0.0034	
Forward Transconductance ^a	9fs	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 20 \text{ A}$	81	169	S
Body Diode Voltage	V _{SD}	I _S = 10 A	0.71	0.72	V
Dynamic ^b					
Input Capacitance	C _{iss}	V_{DS} = 20 V, V_{GS} = 0 V, f = 1 MHz	5260	5286	pF
Output Capacitance	C _{oss}		721	705	
Reverse Transfer Capacitance	C _{rss}		292	283	
Total Gate Charge	Qg	$V_{DS} = 20 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 20 \text{ A}$	87	87	nC
Gate-Source Charge	Q _{gs}		15.3	15.3	
Gate-Drain Charge	Q _{gd}		12.2	12.2	

Notes

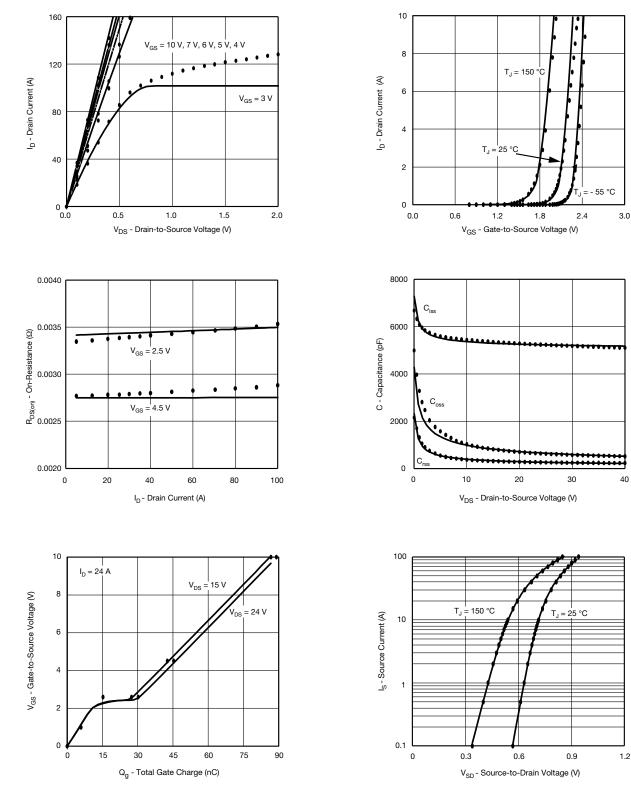
a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%.$

b. Guaranteed by design, not subject to production testing.



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COMPARISON OF MODEL WITH MEASURED DATA T_J = 25 °C, unless otherwise noted



Note

• Dots and squares represent measured data.

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